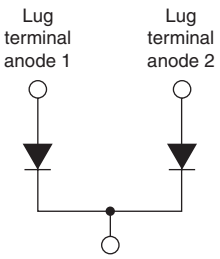
Schottky Rectifier, 200 A

TO-244



FEATURES

- 175 °C T_J operation
- Center tap module
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead (Pb)-free ("PbF" suffix)
- Designed and qualified for industrial level

Pb-free
RoHS COMPLIANT

DESCRIPTION

The 201CNQ045PbF center tap Schottky rectifier module has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in high current switching power supplies, converters, freewheeling diodes, welding, and reverse battery protection.

PRODUCT SUMMARY	
$I_{F(AV)}$	200 A
V_R	45 V

MAJOR RATINGS AND CHARACTERISTICS			
SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	200	A
V_{RRM}		45	V
I_{FSM}	t_p = 5 µs sine	16 000	A
V_F	100 Apk, T_J = 125 °C (per leg)	0.58	V
T_J	Range	- 55 to 175	°C

VOLTAGE RATINGS			
PARAMETER	SYMBOL	201CNQ045PbF	UNITS
Maximum DC reverse voltage	V_R	45	V
Maximum working peak reverse voltage	V_{RWM}		

ABSOLUTE MAXIMUM RATINGS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current See fig. 5	per device	$I_{F(AV)}$	50 % duty cycle at T_C = 146 °C, rectangular waveform	200	A
	per leg			100	
Maximum peak one cycle non-repetitive surge current per leg See fig. 7		I_{FSM}	5 µs sine or 3 µs rect. pulse; Following any rated load condition and with rated V_{RRM} applied	16 000	A
			10 ms sine or 6 ms rect. pulse; Following any rated load condition and with rated V_{RRM} applied	2000	
Non-repetitive avalanche energy per leg		E_{AS}	T_J = 25 °C, I_{AS} = 17 A, L = 1 mH	135	mJ
Repetitive avalanche current per leg		I_{AR}	Current decaying linearly to zero in 1 µs Frequency limited by T_J maximum V_A = 1.5 x V_R typical	20	A

ELECTRICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop per leg See fig. 1	V_{FM} (1)	100 A	T_J = 25 °C	0.67	V
		200 A		0.81	
		100 A	T_J = 125 °C	0.58	
		200 A		0.71	
Maximum reverse leakage current per leg See fig. 2	I_{RM} (1)	T_J = 25 °C	V_R = Rated V_R	10	mA
		T_J = 125 °C		90	
Maximum junction capacitance per leg	C_T	V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 °C		5200	pF
Typical series inductance per leg	L_S	From top of terminal hole to mounting plane		7.0	nH
Maximum voltage rate of change	dV/dt	Rated V_R		10 000	V/µs

Note

(1) Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS

PARAMETER		SYMBOL	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range		T_J, T_{Stg}	- 55	-	175	°C
Thermal resistance, junction to case	per leg	R_{thJC}	-	-	0.38	°C/W
	per module		-	-	0.19	
Thermal resistance, case to heatsink		R_{thCS}	-	0.10	-	
Weight			-	68	-	g
				2.4		oz.
Mounting torque			35.4 (4)	-	53.1 (6)	lbf · in (N · m)
Mounting torque center hole			30 (3.4)	-	40 (4.6)	
Terminal torque			30 (3.4)	-	44.2 (5)	
Vertical pull			-	-	80	lbf · in
2" lever pull			-	-	35	

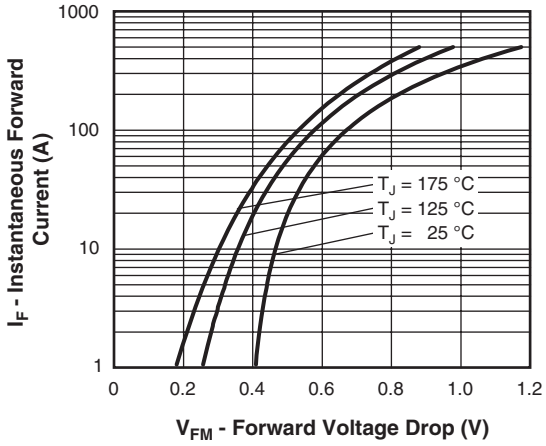


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

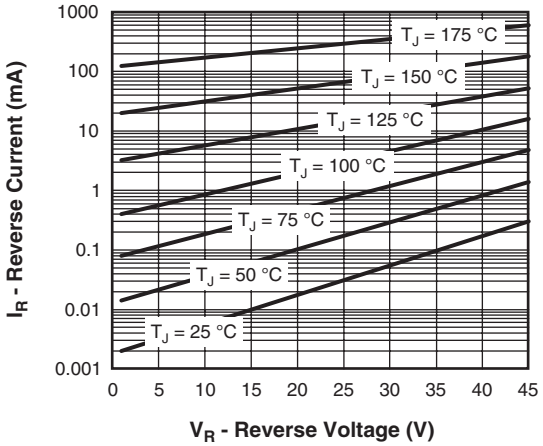


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

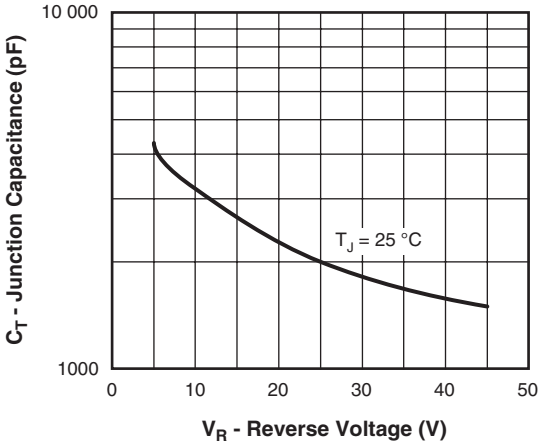


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

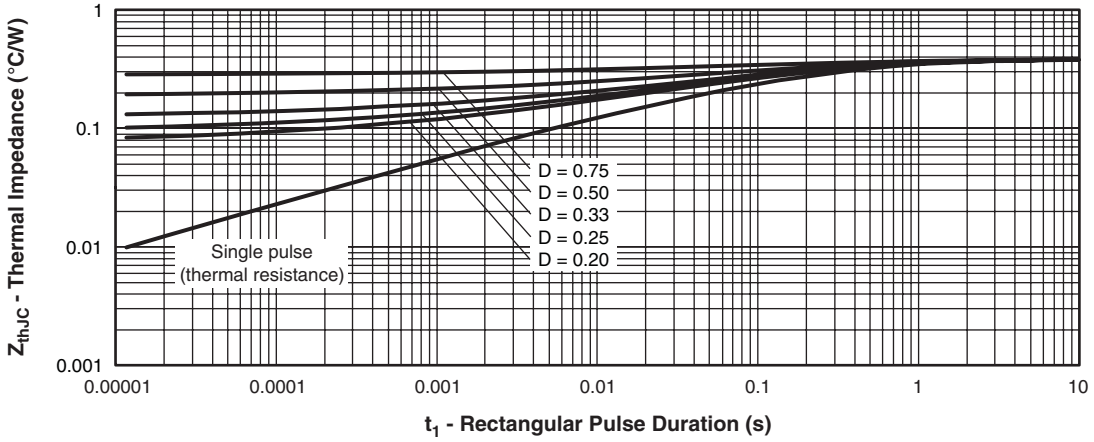


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

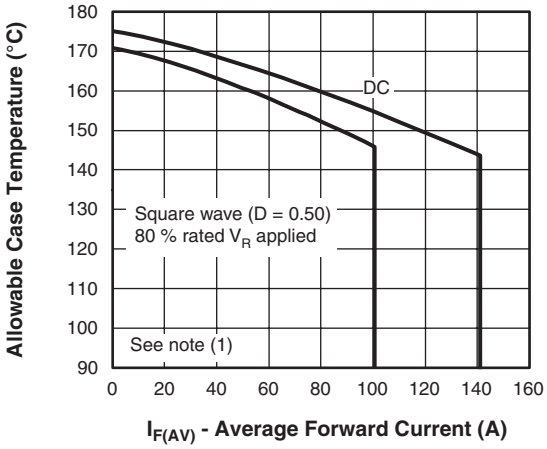


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

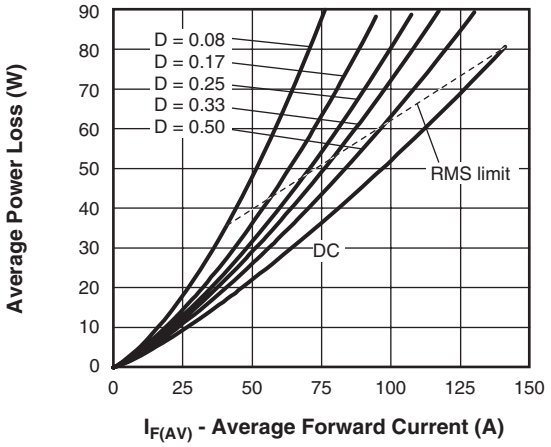


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

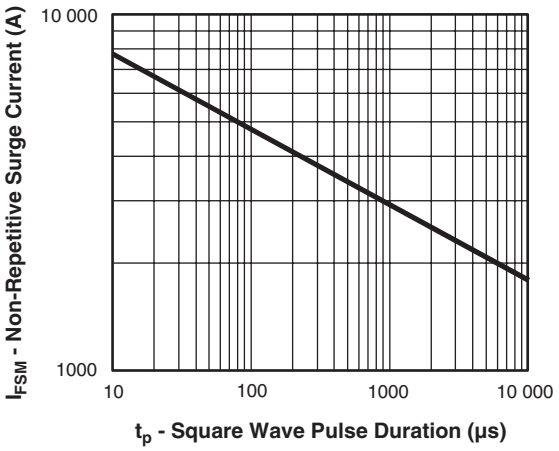


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

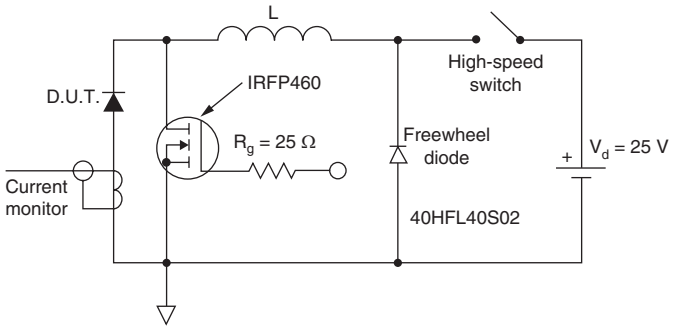


Fig. 8 - Unclamped Inductive Test Circuit

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;
Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at ($I_{F(AV)}$/D) (see fig. 6);
Pd_{REV} = Inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = 80 % rated V_R

ORDERING INFORMATION TABLE

Device code

20	1	C	N	Q	045	PbF
①	②	③	④	⑤	⑥	⑦

- 1 - Average current rating (x 10)
- 2 - Product silicon identification
- 3 - C = Circuit configuration
- 4 - N = Not isolated
- 5 - Q = Schottky rectifier diode
- 6 - Voltage rating (045 = 45 V)
- 7 - Lead (Pb)-free

LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95021

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